onsemi

TinyLogic HST 2-Input NOR Gate

NC7ST02

Description

The NC7ST02 is a single 2–Input high performance CMOS NOR Gate, with TTL-compatible inputs. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation. ESD protection diodes inherently guard both inputs and output with respect to the V_{CC} and GND rails. High gain circuitry offers high noise immunity and reduced sensitivity to input edge rate. The TTL-compatible inputs facilitate TTL to NMOS / CMOS interfacing. Device performance is similar to MM74HCT but with 1/2 the output current drive of HC / HCT.

Features

- Space Saving SOT23-5, SC-74A and SC-88A 5-Lead Package
- Ultra Small MicroPakTM Leadless Package
- High Speed: $t_{PD} < 7$ ns Typ, $V_{CC} = 5$ V, $C_L = 15$ pF
- Low Quiescent Power: $I_{CC} < 1 \mu A$ Typ, $V_{CC} = 5.5 V$
- Balanced Output Drive: 2 mA IOL, -2 mA IOH
- TTL-compatible Inputs
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

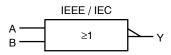
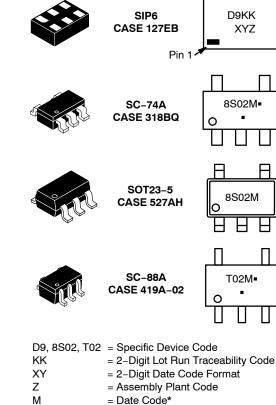


Figure 1. Logic Symbol



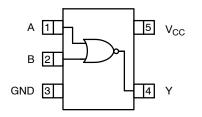
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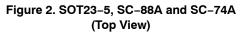
ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 4 of this data sheet.

MARKING DIAGRAMS

Pin Configurations





PIN DESCRIPTIONS

Pin Name	Description
A, B	Inputs
Y	Output
NC	No Connect

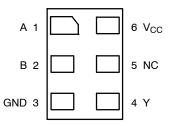


Figure 3. MicroPak (Top Through View)

FUNCTION TABLE $(Y = \overline{A + B})$

Inp	Output	
А	В	Y
L	L	Н
L	н	L
н	L	L
Н	Н	L

H = HIGH Logic Level L = LOW Logic Level

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage	Supply Voltage		6.5	V
Ι _{ΙΚ}	DC Input Diode Current	V _{IN} < 0 V	-	-20	mA
		$V_{IN} > V_{CC}$	-	+20	
V _{IN}	DC Input Voltage		-0.5	V _{CC} + 0.5	V
I _{OK}	DC Output Diode Current V _{OUT} < 0 V		-	-20	mA
		V _{OUT} > V _{CC}	-	+20	
V _{OUT}	Output Voltage		-0.5	V _{CC} + 0.5	V
I _{OUT}	DC Output Source or Sink Current		-	±12.5	mA
$I_{\rm CC}$ or $I_{\rm GND}$	DC V _{CC} or Ground Current per Sup	oply Pin	-	±25	mA
T _{STG}	Storage Temperature		-65	+150	°C
TJ	Junction Temperature		-	+150	°C
ΤL	Lead Temperature (Soldering, 10 Seconds)		-	+260	°C
PD	Power Dissipation in Still Air	SC-74A / SOT23-5	-	390	mW
		SC-88A	-	332	1
		MicroPak-6	-	812	1

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage		4.5	5.5	V
VI	Input Voltage		0	V _{CC}	V
Vo	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 5.0 V	0	10	ns/V
θ_{JA}	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTICAL CHARACTERISTICS

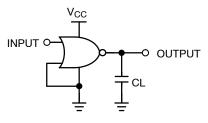
				-	Γ _A = +25°C	;	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage	4.5 – 5.5		2.0	-	-	2.0	-	V
V _{IL}	LOW Level Input Voltage	4.5 – 5.5		-	-	0.8	-	0.8	V
V _{OH}	HIGH Level Output Voltage	4.5 4.5	$\begin{split} I_{OH} &= -20 \ \mu A \\ V_{IN} &= V_{IH} \ or \ V_{IL} \\ I_{OH} &= -2 \ m A \end{split}$	4.4 4.18	4.5 4.35	_	4.4 4.13	-	V
V _{OL}	LOW Level Output Voltage	4.5 4.5	$\begin{split} I_{OL} &= 20 \; \mu A \\ V_{IN} &= V_{IH} \; \text{or} \; V_{IL} \\ I_{OL} &= 2 \; m A \end{split}$	-	0 0.10	0.1 0.26	-	0.1 0.33	V
I _{IN}	Input Leakage Current	5.5	$0V \leq V_{IN} \leq 5.5 \ V$	-	-	±0.1	-	±1.0	μA
I _{CC}	Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$ or GND	-	-	1.0	-	10.0	μA
I _{CCT}	I _{CC} per Input	5.5	One Input $V_{IN} = 0.5 V \text{ or}$ 2.4 V, Other Input V_{CC} or GND	_	-	2.0	_	2.9	mA

AC ELECTRICAL CHARACTERISTICS

				-	T _A = +25°C	2	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay (Figure 4, 6)	5.0	C _L = 15 pF	-	3.5	12	-	-	ns
				-	6.3	17	-	-	
		4.5	C _L = 50 pF	-	6.1	16	-	20	
				-	11.7	27	-	31	
		5.5		-	4.2	14	-	18	
				-	11.4	26	-	30	
t _{TLH} , t _{THL}	Output Transition Time	5.0	C _L = 15 pF	-	4	10	-	-	ns
	(Figure 4, 6)	4.5	C _L = 50 pF	-	11	25	-	31	
		5.5		-	10	21	-	26	
C _{IN}	Input Capacitance	Open		-	2	10	-	-	pF
C _{PD}	Power Dissipation Capacitance (Figure 5)	5.0	(Note 2)	_	6	-	-	-	pF

2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current. Current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 5). C_{PD} is related to I_{CCD} dynamic operating current by the expression: $I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CCstatic})$.

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR = 1.0 MHz; t_W = 500 ns

Figure 4. AC Test Circuit

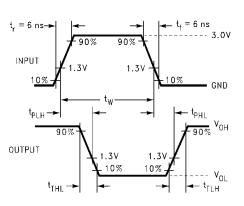
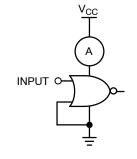


Figure 6. AC Waveforms



Input = AC Waveform; PRR = Variable; Duty Cycle = 50%.

Figure 5. I_{CCD} Test Circuit

ORDERING INFORMATION Order Number Top Mark **Package Description** Shipping[†] NC7ST02M5X 8S02 SC-74A 3000 / Tape & Reel NC7ST02M5X-L22090 SOT23-5 3000 / Tape & Reel 8S02 NC7ST02P5X T02 SC-88A 3000 / Tape & Reel NC7ST02P5X-L22057 T02 SC-88A 3000 / Tape & Reel NC7ST02L6X D9 SIP6, MicroPak 5000 / Tape & Reel

NC7ST02L6X-L22175 D9 SIP6, MicroPak 5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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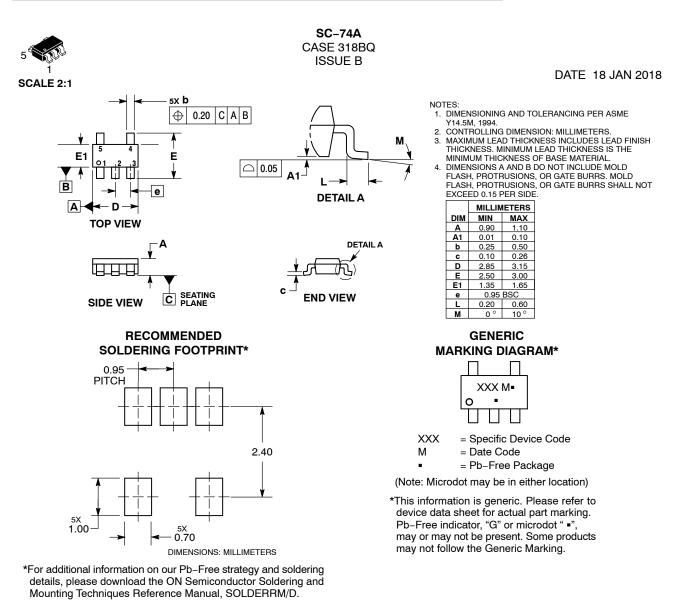


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DATE 31 AUG 2016







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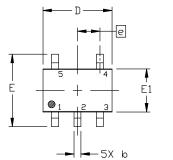
SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

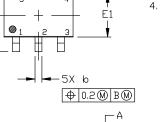
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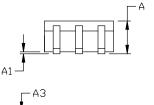
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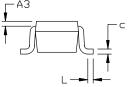
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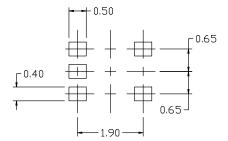
DATE 11 APR 2023











RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS				
MIU	MIN,	NDM.	MAX.		
A	0.80	0.95	1.10		
A1			0.10		
A3	0.20 REF				
b	0.10	0.20	0.30		
С	0.10		0.25		
D	1.80	2.00	5'50		
E	2.00	2.10	5'50		
E1	1.15	1.25	1.35		
e	0.65 BSC				
L	0.10	0.15	0.30		

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

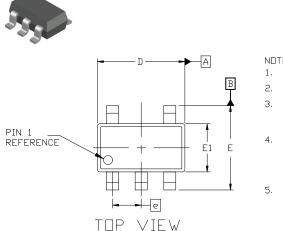
Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device
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DESCRIPTION:	DESCRIPTION: SC-88A (SC-70-5/SOT-353)				PAGE 1 OF 1

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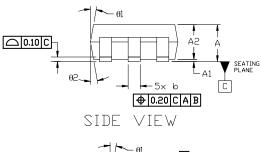


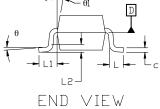
SOT-23, 5 Lead CASE 527AH **ISSUE A**

DATE 09 JUN 2021

NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.





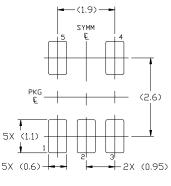
GENERIC **MARKING DIAGRAM***



XXX = Specific Device Code = Date Code М

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS					
DIM	MIN.	NDM.	MAX.			
Α	0.90	—	1.45			
A1	0.00	_	0.15			
A2	0.90	1.15	1.30			
b	0.30	—	0.50			
С	0.08		0.22			
D	2.90 BSC					
E	2	2.80 BSC				
E1	1	1.60 BSC				
е	0.95 BSC					
L	0.30	0.45	0.60			
L1	0.60 REF					
L2	0.25 REF					
θ	0*	4°	8*			
01	0*	10°	15°			
θ 2	0°	10°	15°			



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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